Pin Descriptions

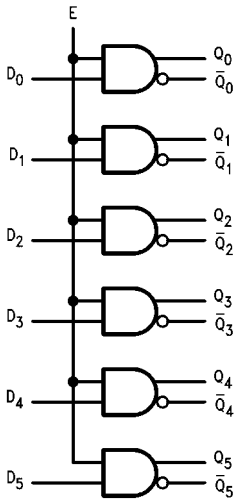
Pin Names	Description
D_0–D_5	Data Inputs
E	Enable Input
Q_0–Q_5	Data Outputs
$\overline{Q}_0$–$\overline{Q}_5$	Complementary Data Outputs

Truth Table

Inputs		Outputs	
D_n	E	Q_n	$\overline{Q}_n$
X	L	L	H
L	H	L	H
H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature (T_{STG})	−65°C to +150°C
Maximum Junction Temperature (T_J)	+150°C
V_{EE} Pin Potential to Ground Pin	−7.0V to +0.5V
V_{TTL} Pin Potential to Ground Pin	−0.5V to +6.0V
Input Voltage (DC)	−0.5V to +6.0V
Output Current (DC Output HIGH)	−50 mA
ESD (Note 2)	≥2000V

Recommended Operating Conditions

Case Temperature (T_C)	
Commercial	0°C to +85°C
Industrial	−40°C to +85°C
Supply Voltage (V_{EE})	−5.7V to −4.2V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: ESD testing conforms to MIL-STD-883, Method 3015.

Commercial Version

DC Electrical Characteristics (Note 3)

V_{EE} = −4.2V to −5.7V, V_{CC} = V_{CCA} = GND, T_C = 0°C to +85°C, V_{TTL} = +4.5V to +5.5V

Symbol	Parameter	Min	Typ	Max	Units	Conditions	
V_{OH}	Output HIGH Voltage	−1025	−955	−870	mV	V_{IN} = $V_{IH\ (Max)}$	Loading with
V_{OL}	Output LOW Voltage	−1830	−1705	−1620		or $V_{IL\ (Min)}$	50Ω to −2.0V
V_{OHC}	Output HIGH Voltage	−1035			mV	V_{IN} = $V_{IH(Min)}$	Loading with
V_{OLC}	Output LOW Voltage			−1610		or $V_{IL\ (Max)}$	50Ω to −2.0V
V_{IH}	Input HIGH Voltage	2.0		5.0	V	Guaranteed HIGH Signal for All Inputs	
V_{IL}	Input LOW Voltage	0		0.8	V	Guaranteed LOW Signal for All Inputs	
V_{CD}	Input Clamp Diode Voltage	−1.2			V	I_{IN} = −18 mA	
I_{IH}	Input HIGH Current					V_{IN} = +2.4V,	
	Data			20	μA	All Other Inputs V_{IN} = GND	
	Enable			120			
	Input HIGH Current			1.0	mA	V_{IN} = +5.5V,	
	Breakdown Test, All Inputs					All Other Inputs = GND	
I_{IL}	Input LOW Current					V_{IN} = +0.4V,	
	Data	−0.9			mA	All Other Inputs V_{IN} = V_{IH}	
	Enable	−5.4					
I_{EE}	V_{EE} Power Supply Current	−70	−45	−22	mA	All Inputs V_{IN} = +4.0V	
I_{TTL}	V_{TTL} Power Supply Current		25	38	mA	All Inputs V_{IN} = GND	

Note 3: The specified limits represent the "worst case" value for the parameter. Since these values normally occur at the temperature extremes, additional noise immunity and guardbanding can be achieved by decreasing the allowable system operating ranges. Conditions for testing shown in the tables are chosen to guarantee operation under "worst case" conditions.

DIP AC Electric Characteristics

V_{EE} = −4.2V to −5.7V, V_{CC} = V_{CCA} = GND, V_{TTL} = +4.5V to +5.5V

Symbol	Parameter	T_C = 0°C		T_C = +25°C		T_C = +85°C		Units	Conditions
		Min	Max	Min	Max	Min	Max		
t_{PLH}	Propagation Delay	0.50	3.00	0.50	2.90	0.50	3.00	ns	Figures 1, 2
t_{PHL}	Data and Enable to Output								
t_{TLH}	Transition Time	0.45	1.80	0.45	1.80	0.45	1.80	ns	
t_{THL}	20% to 80%, 80% to 20%								

Commercial Version (Continued)
SOIC and PLCC AC Electrical Characteristics

V_{EE} = –4.2V to –5.7V, V_{CC} = V_{CCA} = GND, V_{TTL} = +4.5V to +5.5V

Symbol	Parameter	T_C = 0°C		T_C = +25°C		T_C = +85°C		Units	Conditions
		Min	Max	Min	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay Data and Enable to Output	0.50	2.80	0.50	2.70	0.50	2.80	ns	Figures 1, 2
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.45	1.70	0.45	1.70	0.45	1.70	ns	
t_{OSHL}	Maximum Skew Common Edge Output-to-Output Variation Data to Output Path		0.95		0.95		0.95	ns	PLCC Only (Note 4)
t_{OSLH}	Maximum Skew Common Edge Output-to-Output Variation Data to Output Path		0.70		0.70		0.70	ns	PLCC Only (Note 4)
t_{OST}	Maximum Skew Opposite Edge Output-to-Output Variation Data to Output Path		1.60		1.60		1.60	ns	PLCC Only (Note 4)
t_{PS}	Maximum Skew Pin (Signal) Transition Variation Data to Output Path		1.20		1.20		1.20	ns	PLCC Only (Note 4)

Note 4: Output-to-Output Skew is defined as the absolute value of the difference between the actual propagation delay for any outputs within the same packaged device. The specifications apply to any outputs switching in the same direction either HIGH-to-LOW (t_{OSHL}), or LOW-to-HIGH (t_{OSLH}), or in opposite directions both HL and LH (t_{OST}). Parameters t_{OST} and t_{PS} guaranteed by design.

Industrial Version

DC Electrical Characteristics (Note 5)

V_{EE} = −4.2V to −5.7V, V_{CC} = V_{CCA} = GND, T_C = −40°C to +85°C, V_{TTL} = +4.5V to +5.5V

Symbol	Parameter	T_C = −40°C		T_C = 0°C to +85°C		Units	Conditions	
		Min	Max	Min	Max			
V_{OH}	Output HIGH Voltage	−1085	−870	−1025	−870	mV	V_{IN} = $V_{IH\ (Max)}$ or $V_{IL\ (Min)}$	Loading with 50Ω to −2.0V
V_{OL}	Output LOW Voltage	−1830	−1575	−1830	−1620			
V_{OHC}	Output HIGH Voltage	−1095		−1035		mV	V_{IN} = $V_{IH(Min)}$ or $V_{IL\ (Max)}$	Loading with 50Ω to −2.0V
V_{OLC}	Output LOW Voltage		−1565		−1610			
V_{IH}	Input HIGH Voltage	2.0	5.0	2.0	5.0	V	Guaranteed HIGH Signal for All Inputs	
V_{IL}	Input LOW Voltage	0	0.8	0	0.8	V	Guaranteed LOW Signal for All Inputs	
V_{CD}	Input Clamp Diode Voltage	−1.2		−1.2		V	I_{IN} = −18 mA	
I_{IH}	Input HIGH Current						V_{IN} = +2.4V,	
	Data		20		20	μA	All Other Inputs V_{IN} = GND	
	Enable		120		120			
	Input HIGH Current Breakdown Test, All Inputs		1.0		1.0	mA	V_{IN} = +5.5V, All Other Inputs = GND	
I_{IL}	Input LOW Current						V_{IN} = +0.4V,	
	Data	−0.9		−0.9		mA	All Other Inputs V_{IN} = V_{IH}	
	Enable	−5.4		−5.4				
I_{EE}	V_{EE} Power Supply Current	−70	−22	−70	−22	mA	All Inputs V_{IN} = +4.0V	
I_{TTL}	V_{TTL} Power Supply Current		38		38	mA	All Inputs V_{IN} = GND	

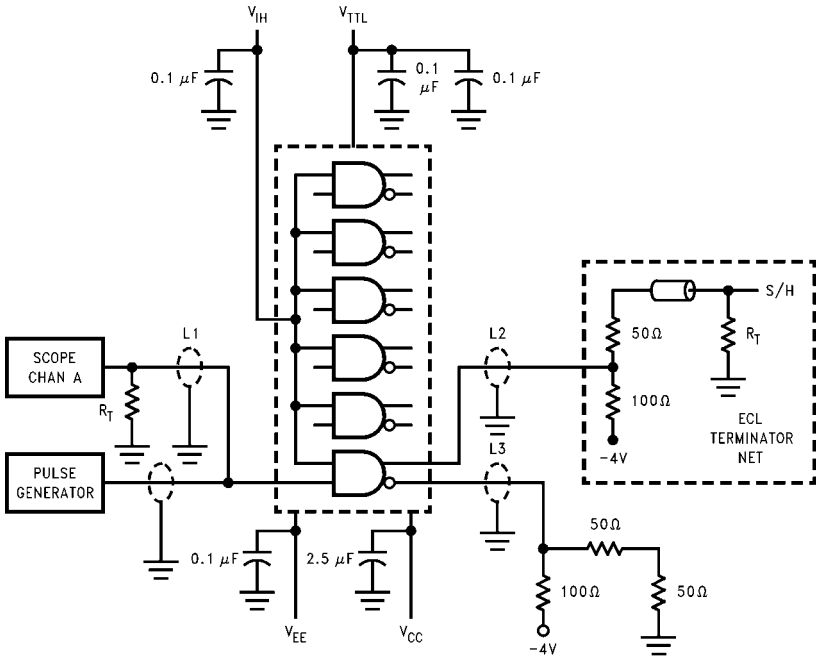
Note 5: The specified limits represent the "worst case" value for the parameter. Since these values normally occur at the temperature extremes, additional noise immunity and guardbanding can be achieved by decreasing the allowable system operating ranges. Conditions for testing shown in the tables are chosen to guarantee operation under "worst case" conditions.

AC Electrical Characteristics

V_{EE} = −4.2V to −5.7V, V_{CC} = V_{CCA} = GND, V_{TTL} = +4.5V to +5.5V

Symbol	Parameter	T_C = −40°C		T_C = +25°C		T_C = +85°C		Units	Conditions
		Min	Max	Min	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay Data and Enable to Output	0.50	2.80	0.50	2.70	0.50	2.80	ns	Figures 1, 2
t_{TLH} t_{THL}	Transition Times 20% to 80%, 80% to 20%	0.35	1.80	0.45	1.70	0.45	1.70	ns	Figures 1, 2

Test Circuit



Note:

- V_{CC}, V_{CCA} = 0V, V_{EE} = −4.5V, V_{TTL} = +5.0V, V_{IH} = +3.0V
- L1, L2 and L3 = equal length 50Ω impedance lines
- R_T = 50Ω terminator internal to scope
- Decoupling 0.1 μF from GND to V_{CC}, V_{EE} and V_{TTL}
- All unused outputs are loaded with 50Ω to −2V or with equivalent ECL terminator network
- C_L = Fixture and stray capacitance ≤ 3 pF

FIGURE 1. AC Test Circuit

Switching Waveform

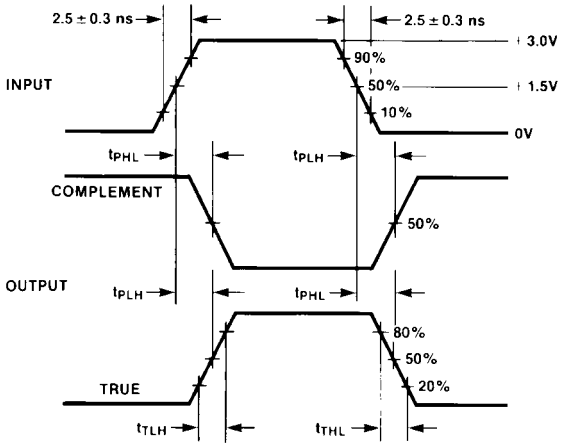
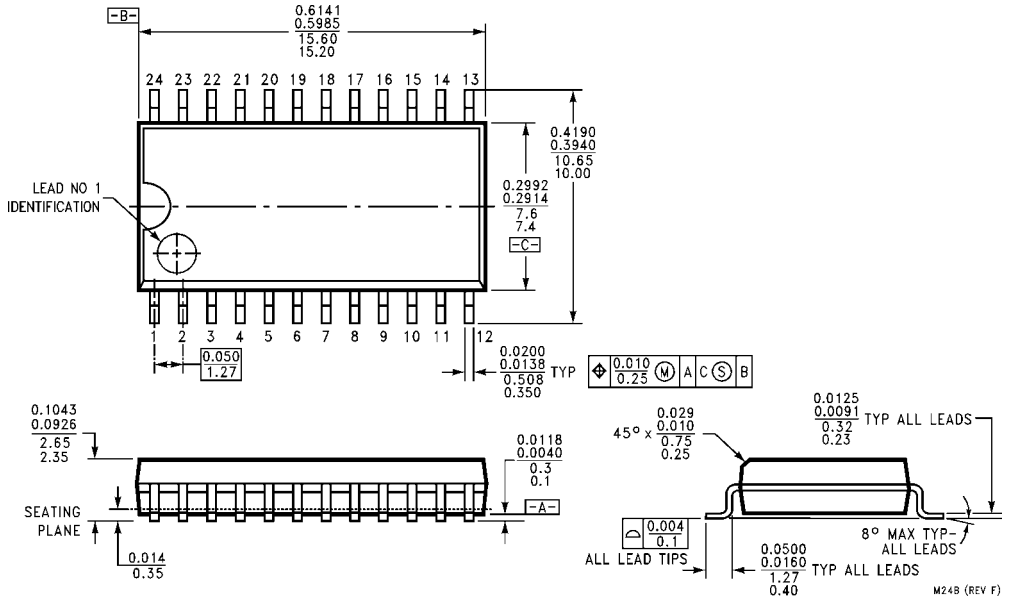
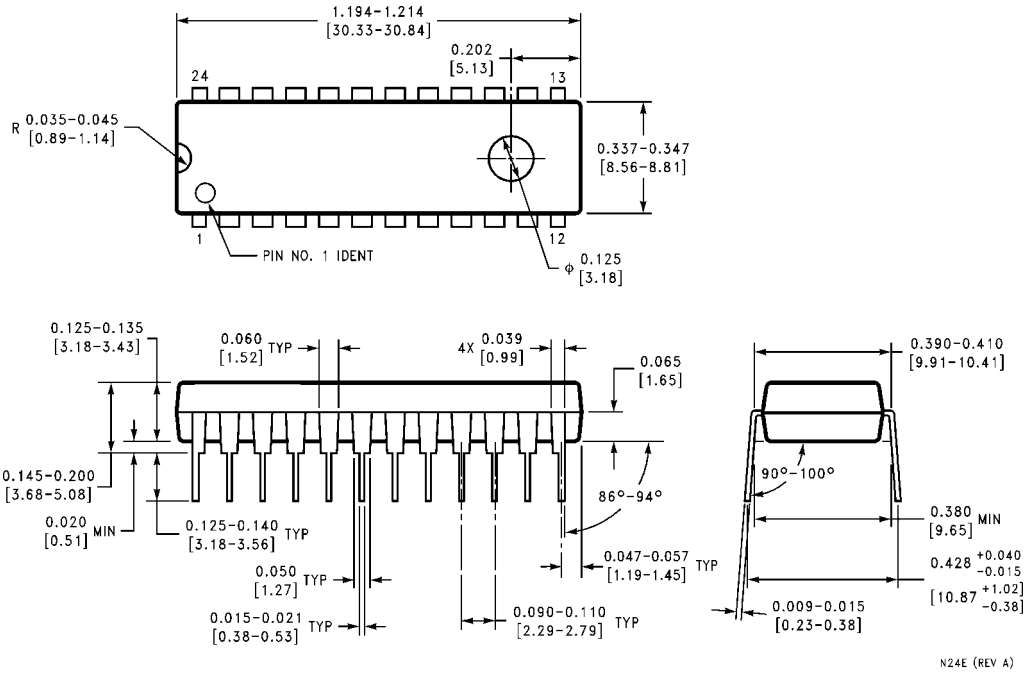


FIGURE 2. Propagation Delay and Transition Times

Physical Dimensions inches (millimeters) unless otherwise noted

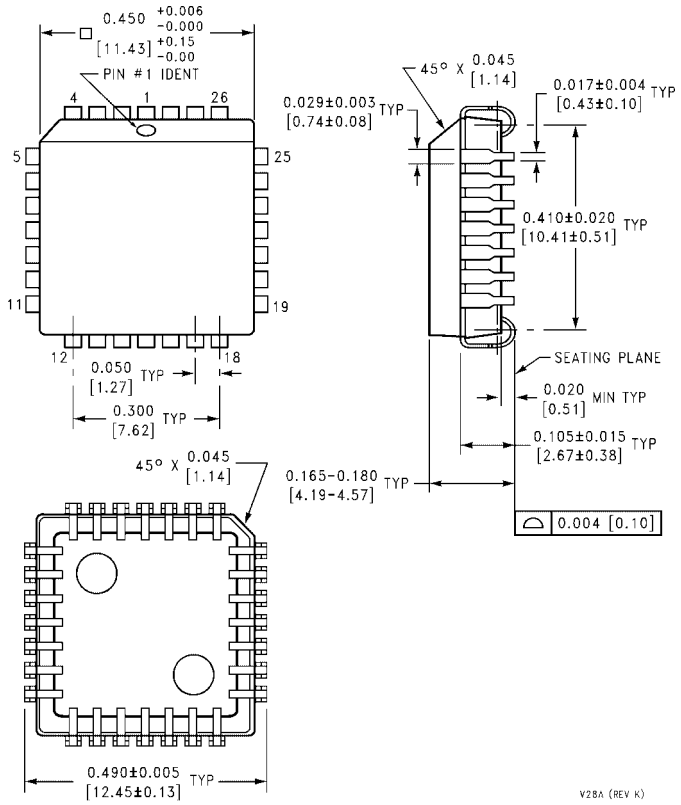


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.400 Wide
Package Number N24E

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square
Package Number V28A

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